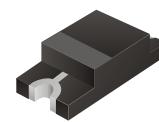


SMD Switching Diode

COMCHIP
www.comchip.com.tw

CDSN4148

High Speed



Features

Designed for mounting on small surface.

High speed switching.

High mounting capability, strong surge withstand, high reliability.

Mechanical data

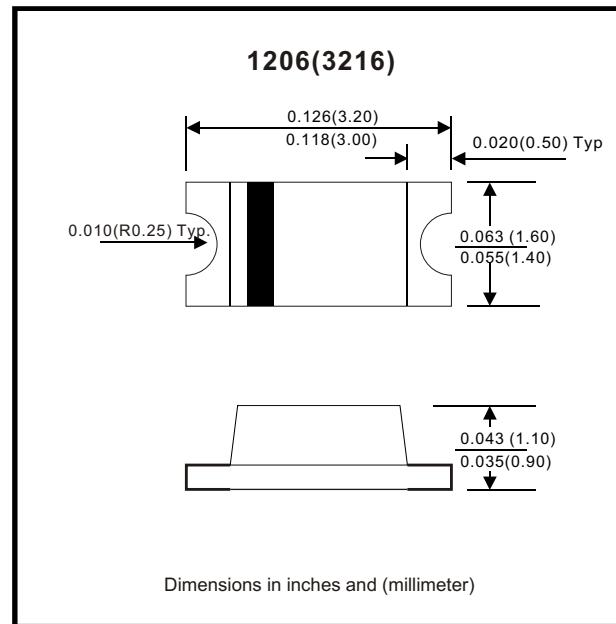
Case: 1206(3216) standard package, molded plastic.

Terminals: Solder plated, solderable per MIL-STD-750, method 2026.

Polarity: Indicated by cathode band.

Mounting position: Any.

Weight: 0.0085 gram. (approximately)



Dimensions in inches and (millimeter)

Maximum Rating (at TA = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Repetitive peak reverse voltage		V _{RRM}			100	V
Reverse voltage		V _R			75	V
Average forward current		I _o			150	mA
Forward current , surge peak	T _p = 1us T _p = 1s	I _{FSM}		4 1		A
Power Dissipation		P _D			350	mW
Storage temperature		T _{TG}	-55		+175	°C
Junction temperature		T _j	-55		+175	°C

Electrical Characteristics (at TA = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	I _F = 50 mA DC	V _F			1.0	V
Reverse current	V _R = 20 V V _R = 75 V	I _R			25 2.5	nA uA
Capacitance between terminals	f = 1MHz, and 0 VDC reverse voltage	C _T			3	pF
Reverse recovery time	V _R = 6V, I _F = 10 mA, R _L = 50 ohms	T _{rr}			4	ns

RATING AND CHARACTERISTIC CURVES (CDSN4148)

Fig. 1 - Forward characteristics

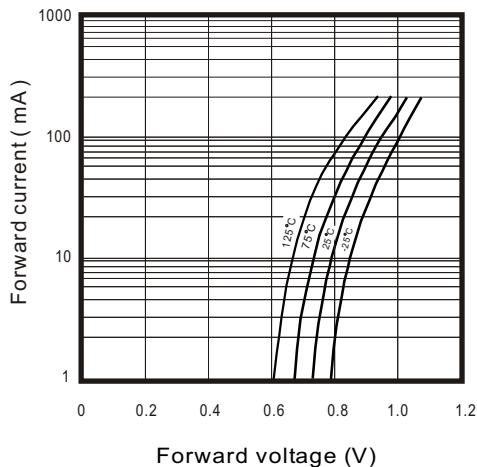


Fig. 2 - Reverse characteristics

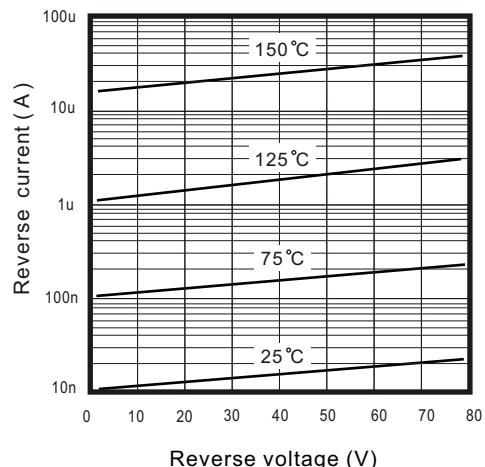


Fig. 3 - Capacitance between terminals characteristics

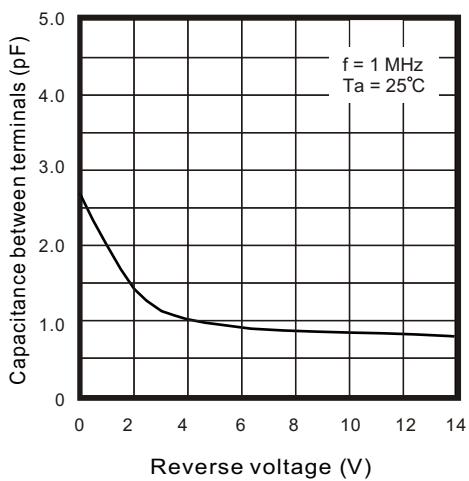


Fig. 4 - Current derating curve

